



SEARCHED			
Class	Sub.	Date	Exmr.
438 257	207 316 335 347 407 409 350		

INTERFERENCE SEARCHED			
Class	Sub.	Date	Exmr.

SEARCH NOTES (INCLUDING SEARCH STRATEGY)		
	Date	Exmr.
EAST 1.3 APPLICANT FORMS A LATERAL TRANSISTOR BY FORMING THE SOURCE/DRAIN REGIONS BEFORE FORMING A GATE OXIDE IN GATE REGION	5/23/03	